# Non-Inverting Buffer with Open Drain Output

The NLU1G07 is an advanced high-speed CMOS non-inverting buffer with open drain output in ultra-small footprint.

The NLU1G07 input and output structures provide protection when voltages up to 7.0 V are applied, irregardless of the supply voltage.

#### **Features**

- High Speed:  $t_{PD} = 3.8 \text{ ns (Typ)} @ V_{CC} = 5.0 \text{ V}$
- Low Power Dissipation:  $I_{CC} = 1 \mu A$  (Max) at  $T_A = 25^{\circ}C$
- Power Down Protection Provided on inputs
- Balanced Propagation Delays
- Overvoltage Tolerant (OVT) Input and Output Pins
- Ultra-Small Pb-Free Package
- This is a Pb-Free Device

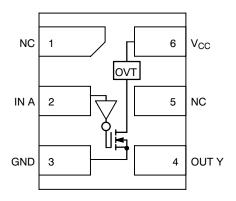


Figure 1. Pinout (Top View)

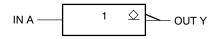


Figure 2. Logic Symbol



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http://onsemi.com

#### **MARKING DIAGRAM**





UDFN6 MU SUFFIX CASE 517AA

LE, U = Device Marking
M = Date Code
• Pb-Free Package

#### **PIN ASSIGNMENT**

1	NC
2	IN A
3	GND
4	OUT Y
5	NC
6	V <sub>CC</sub>

## **FUNCTION TABLE**

Α	Υ
L	L
H	Z

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

#### **MAXIMUM RATINGS**

Symbol	Parameter		Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +7.0	V
V <sub>IN</sub>	DC Input Voltage		-0.5 to +7.0	V
V <sub>OUT</sub>	DC Output Voltage		-0.5 to +7.0	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	-20	mA
I <sub>OK</sub>	DC Output Diode Current	V <sub>OUT</sub> < GND	±20	mA
Io	DC Output Source/Sink Current		±12.5	mA
I <sub>CC</sub>	DC Supply Current Per Supply Pin		±25	mA
I <sub>GND</sub>	DC Ground Current per Ground Pin		±25	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 Second	onds	TBD	°C
TJ	Junction Temperature Under Bias		TBD	°C
$\theta_{\sf JA}$	Thermal Resistance (Note 1)	UDFN6	TBD	°C/W
$P_{D}$	Power Dissipation in Still Air at 85°C	UDFN6	TBD	mW
MSL	Moisture Sensitivity		Level 1	
F <sub>R</sub>	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V <sub>ESD</sub>		an Body Mode (Note 2) Machine Model (Note 3) I Device Model (Note 4)	> 2000 > 200 N/A	٧
I <sub>LATCHUP</sub>	Latchup Performance Above V <sub>CC</sub> and Below GN	ND at 125°C (Note 5)	±500	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.

- Tested to EIA / JESD22-A114-A.
   Tested to EIA / JESD22-A115-A.
- 4. Tested to JESD22-C101-A.
- 5. Tested to EIA / JESD78.

#### RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
V <sub>CC</sub>	Positive DC Supply Voltage	1.65	5.5	V	
V <sub>IN</sub>	Digital Input Voltage		0	5.5	V
V <sub>OUT</sub>	Output Voltage		0	5.5	V
T <sub>A</sub>	Operating Free-Air Temperature		-55	+125	°C
Δt/ΔV	Input Transition Rise or Fail Rate $ \begin{array}{c} V_{CC} = 3.3 \ V \pm 0.3 \ V \\ V_{CC} = 5.0 \ V \pm 0.5 \ V \end{array} $		0 0	100 20	ns/V

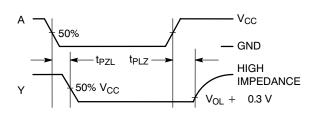
## DC ELECTRICAL CHARACTERISTICS

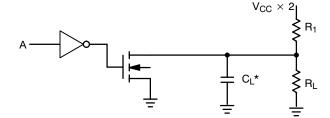
			V <sub>CC</sub>	T,	<sub>A</sub> = 25 °	С	<b>T</b> <sub>A</sub> = -	+85°C		-55°C 125°C	
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V <sub>IH</sub>	Low-Level Input Voltage		1.65	0.75 x V <sub>CC</sub>			0.75 x V <sub>CC</sub>				V
			2.3 to 5.5	0.70 x V <sub>CC</sub>			0.70 x V <sub>CC</sub>				
V <sub>IL</sub>	Low-Level Input Voltage		1.65			0.25 x V <sub>CC</sub>		0.25 x V <sub>CC</sub>		0.25 x V <sub>CC</sub>	V
			2.3 to 5.5			0.30 x V <sub>CC</sub>		0.30 x V <sub>CC</sub>		0.30 x V <sub>CC</sub>	
V <sub>OL</sub>	Low-Level Output Voltage	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 50  \mu\text{A}$	2.0 3.0 4.5		0 0 0	0.1 0.1 0.1		0.1 0.1 0.1		0.1 0.1 0.1	V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 4 \text{ mA}$ $I_{OL} = 8 \text{ mA}$	3.0 4.5			0.36 0.36		0.44 0.44		0.52 0.52	
I <sub>LKG</sub>	Z-State Output Leakage Current	$V_{IN} = V_{IH}, V_{OUT}$ = $V_{CC}$ or GND	5.5			±0.25		±2.5		±5.0	μΑ
I <sub>IN</sub>	Input Leakage Current	0 = V <sub>IN</sub> = 5.5 V	0 to 5.5			±0.1		±1.0		±1.0	μΑ
l <sub>OFF</sub>	Power off Input Leakage Current	$0 \le V_{IN},$ $V_{OUT} = 5.5 V$	0.0			0.25		2.5		5	μΑ
Icc	Quiescent Supply Current	$0 \le V_{IN} \le V_{CC}$	5.5			1.0		20		40	μΑ

## AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$ )

		V <sub>CC</sub>		T,	T <sub>A</sub> = 25 °C		T <sub>A</sub> = +85°C		T <sub>A</sub> = -55°C to +125°C		
Symbol	Parameter	(V)	Test Condition	Min	Тур	Max	Min	Max	Min	Max	Unit
t <sub>PZL</sub>	Output Enable Time, Input A to Output Y	3.0 to 3.6	$R_L = R_1 = 50 \Omega$ , $C_L = 15 pF$		5.0	7.1		8.5		10.0	ns
	Output 1		$R_L = R_1 = 50 \Omega$ , $C_L = 50 pF$		7.5	10.6		12.0		14.5	
		4.5 to 5.5	$R_L = R_1 = 50 \Omega$ , $C_L = 15 pF$		3.8	5.5		6.5		8.0	
			$R_L = R_1 = 50 \ \Omega,$ $C_L = 50 \ pF$		5.3	7.5		8.5		10.0	
t <sub>PLZ</sub>	Output Disable Time	3.0 to 3.6	$R_L = R_1 = 50 \Omega$ , $C_L = 50 pF$		7.5	10.6		12.0		14.5	ns
		4.5 to 5.5	$R_L = R_1 = 50 \Omega$ , $C_L = 50 pF$		5.3	7.5		8.5		10.0	
C <sub>IN</sub>	Input Capacitance				4	10		10		10.0	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 6)	5.0			18						pF

<sup>6.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no-load dynamic power consumption: P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.





\*Includes jig and probe capacitance.  $R_L=R_1=500\;\Omega$ 

Figure 3. Switching Waveforms

Figure 4. Test Circuit

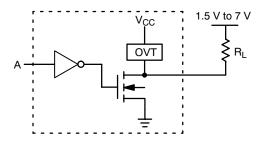


Figure 5. Output Voltage Mismatch Application

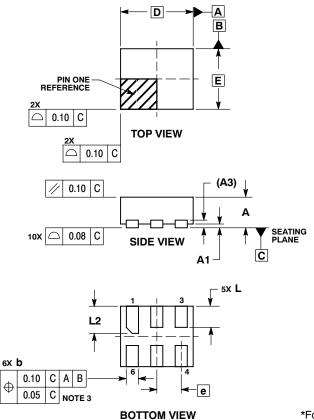
## **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NLU1G07MUTCG	UDFN6 (Pb-Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## PACKAGE DIMENSIONS

UDFN6, 1.2x1.0, 0.4P CASE 517AA-01 **ISSUE B** 



#### NOTES:

- AUTES:

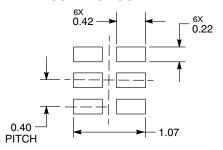
  1. DIMENSIONING AND TOLERANCING PER
  ASME Y14.5M, 1994.

  2. CONTROLLING DIMENSION: MILLIMETERS.

  3. DIMENSION b APPLIES TO PLATED TERMINAL
  AND IS MEASURED BETWEEN 0.25 AND
- 0.30 mm FROM TERMINAL. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIMETERS					
DIM	MIN	MAX				
Α	0.45	0.55				
A1	0.00	0.05				
А3	0.127 REF					
b	0.15	0.25				
D	1.20	BSC				
Е	1.00	BSC				
е	0.40 BSC					
L	0.30	0.40				
12	0.40	0.50				

## **MOUNTING FOOTPRINT\***



**DIMENSIONS: MILLIMETERS** 

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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